CSC 219

Digital Systems. A digital system is a commonation of devices designed to manipulate logical Information or physical quantities that are represented in digital forms te the quantities can take only eliscrete values. This devices are most often electronics but they can also be mechanical magnetic or Preumatus. binary (adding

Analog System

This is a System that contain devices that manipulates Physical quantities that are represented in analog form. In an analog System, the quantities over a continuous range of values.

MB: You can remove Advantages of digetal System

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the fust 2 0 cus + Digital system are easier to

+ Information 5 tora & Accuracy and to maximize the System. + operation can # Digital Oran affected by not * more digital be fabricated

Printations of * The real wo * processing o takes tame.

Voltage Source Sour A voltage So which can pu continuous fo electrons Cor Through the

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device.

information storage Types of vortage source Accuracy and precision are easier + Drock wrange Source a comounto maximize throughout the Theses a clavice waren ned to produces a communications fermation + operation can be programmed voltage output A dweet that are + Digital Circuits are less Nettage to a type of voltage forms te affected by notice. whose polanty remains the take only * More digital circuity can same . Thes type of vottage devices be fabricated on Ic chips. causes the current to move necs but only in one direction conanneal Limitations of Digital systems tinuosiy. Examples of + The real world is analog. direct voltage source are * processing degital signals Cells, battery , Dc generatur. takes tame i t contan NOTE: Polanty is defined as res having two opposite elam-Voltage source and current cal charges, "good" and are Source evil" are examples of com- la A voltage Source is a device quantwhich can produce a produce a Polanty muous continuous force to move elections for continuous voltage) & Acternating Nettage Source This is a device which through the wire connected to stem produces an atternating the two terminals of the direct voltage output. Example to device . a shore a paint screeding to only request

An attemating vertage is a type of vertage where polarly is reversed periodically. Attemating votage causes the ament to move in one direction for a period and then another chrection for another period.

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* Deal Voltage Source

This is a kind of voltage source venore internal resistance is o such that the supply voltage does not change even if the external load resistance is changed.

CURRENT SOURCE

Pleasons or current on a circuit.

Types of current Source

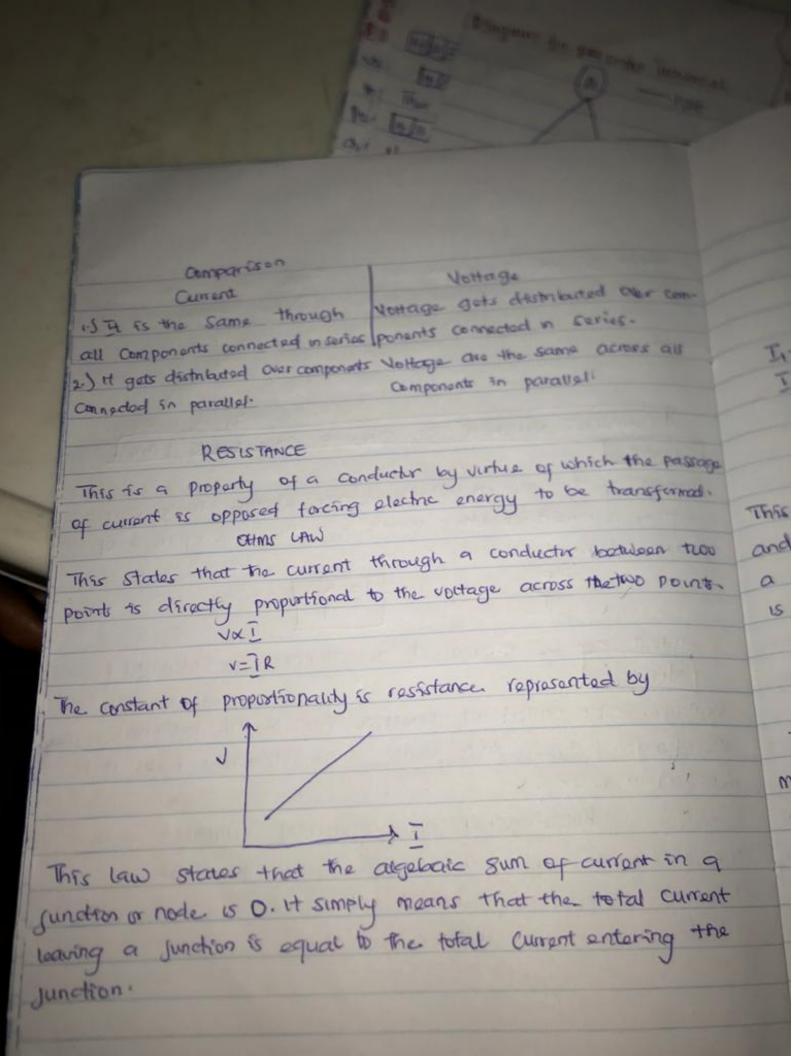
* Direct current source

This is made of a direct voltage source.

xf Attemating current Source

This is a type of current source made of an atternating Vottage source.

ideal Current Source 18 15 a current Soura which provides a constant current what any relation with the voltage Supplied to the polanty dot load. Cument Frictay with ser. CURRENT, NOLTAGE, RESISTANCE AND OHMS LAW sistara Current Current is the rate at which elastric charge flows part a point in a circuit. In other words, it is the rare of flow of en 4 electric charge. 1.e. 1=Q Current can be measured in ampheres or coloumbs persec 1 Vottage vortage also called elactromotive force is the potential differen in charge between two points in an etectrical field. It is measured in voit. Relationship bothoon Current Evoltage Ocurrent is the effect and vortege being the cause 2.) Current cannot from without vottage. d.) Nottage can exist without current.



Therefore - and - can be endmodely - make the day Dingum for pr d over com-145 -I+ I+ - I2- Is - I3=0 icross all I, + I = I 2 + I 5 + I 3 EI=O the passage Kirchoff's voltage haw This state that the algobrasa sum of the product of current nofurmed. and restistances in each of the conductors in any closed parts. In the algobraic sum of the emf in that path en troo a newton Point 15 Zero. EIRF + Zempzo Superposition Theorem This states that in a newton of Isnear resistance containing more than one source of empethe current which flows at any point is the sum of all the current which wall from at that point if each emf is considered separately and all the other emp replaced for the time being by resistances equal to their

OR

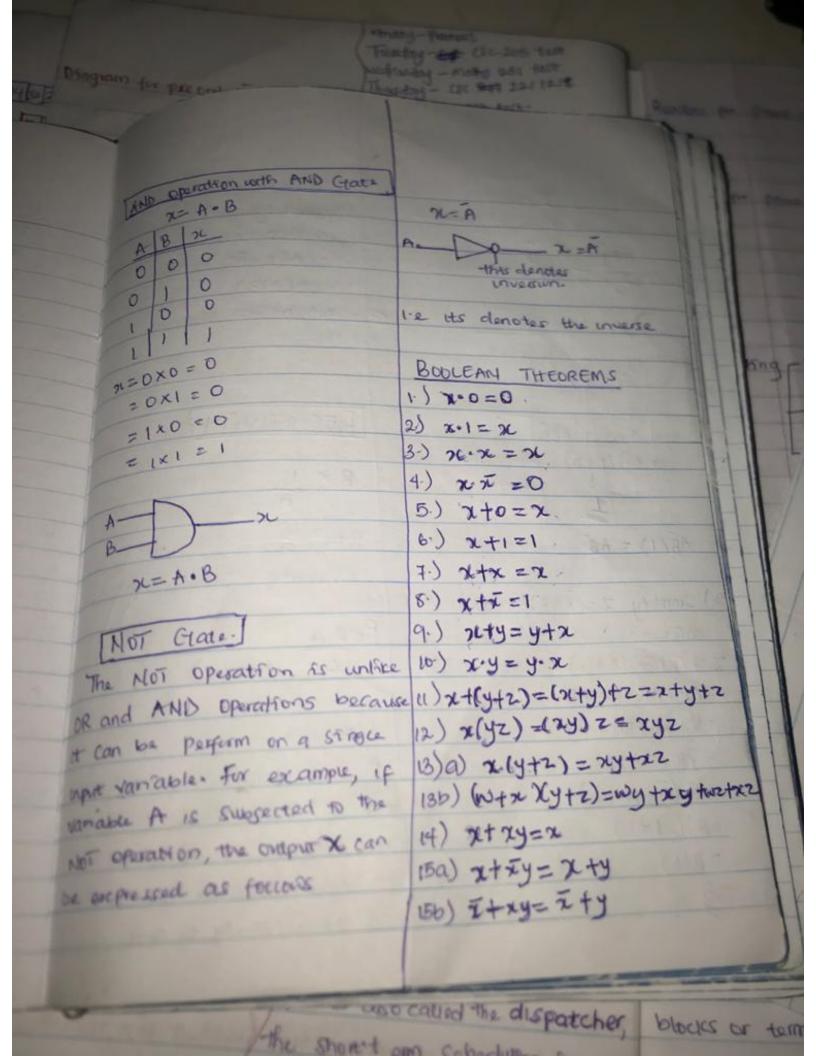
resistances.

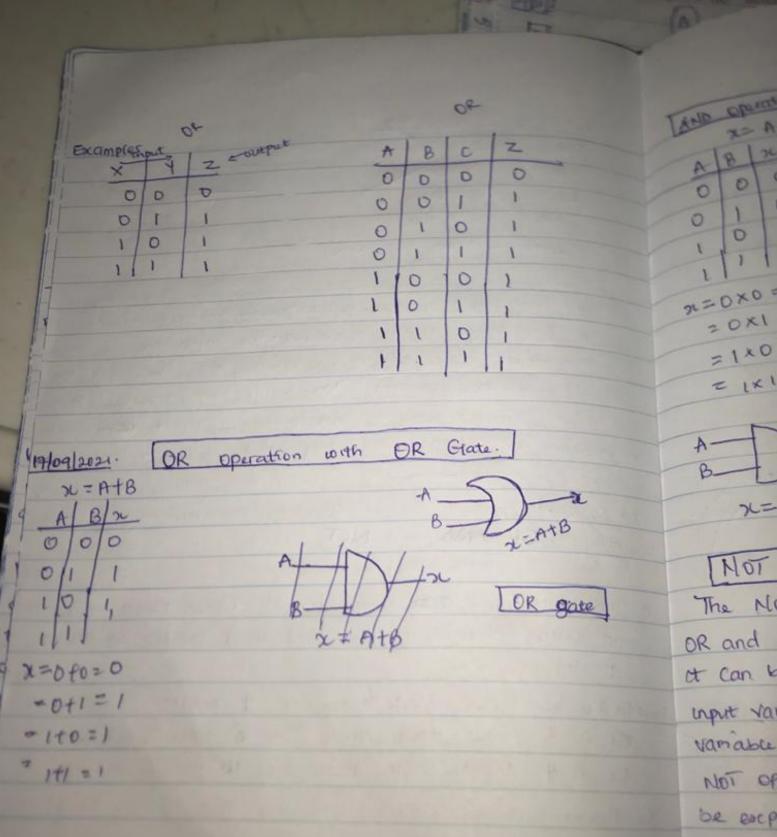
Interval

The current has in a branch of a linear curcuit is oqual to the sum of the current produced by each source with the Other Sources set equal to Zero. Therein Therein Theyerin theorem chau This state that any linear two terminal DC network can be represented by a vottage Sturce in Series with a ranstance Book woon 1001 Boolean Constant and variable. but Boolean algebras differ in a major way from normal algebra algor because boolean constants and variables are allowed to have ru , only two possible values Os or 1. A boolean variable is a num quantity that may different times, It is enther equal to 8 or and 1. A Boolean o and I do not represent actual numbers but oper Instead represent the stage of a voltage variable or what is called its logic level. A voltage in a digital circuit is said A to se at the logic o revel or the logic I level depending ev the actual numeric value - in a digital logic, Several Other CUF terms are used synnonimosty are shown in the table below NB

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	10816 Q	LOGIC 1			
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equal to	OH	on	_	-\Close	
the ?	Low	Itegh		Surte	
	No	Yes			
-	gen Switch	1 closed si	iltch		
an be	1				H
na	Boolean algobi	anka mea	us of expressing	the relationship	p loet-
	woon a logic Cli	cut input o	and output The	inputs are co	nridoced
	Jarfaldes	whose legic	- lovoic at a	15	
and the	nutput level &	because but	y times values	are passible	1 Buotion
algebra	2/10/014 5	0	to Conipa	idd femu	L cridoper
Dave	in boolean algel	ira, there a	o no fractions,	documal, nega	tive
	numbers, square 10	Ots, cube 1	bots, Logarithms	, Immaginary	numbels,
8	and so on. In fact	, in boolean	algobra, then	e are only 3	basic
	perations: OR, A	MD, and 1	JOT.	3	
-	In	rth Tables			110
S	Truth table is	a made made	ins for describ	orna hma a le	2010
	rourt output de	ands on the	on love level	Depends at	the
		heire or in	e rogic reost	Produit CC	
	cust Input.	l a			
AB:	ter a two inpu	it table, th	ere are 9 e	enties.	110-
	per a 3 input	table, t	here are 8 -	table entries	100
	for a 4 Inpu	t table, t	here are 16	table entri	-29
	Number of MAI				
	put high toples				
	Name and Address of the Owner, where the Person of the Owner, where the Person of the Owner, where the Owner, which the Owner, where the Owner, where the Owner, which the Owner		THE RESERVE THE PERSON NAMED IN	Company of the last of the las	and the same of the same of

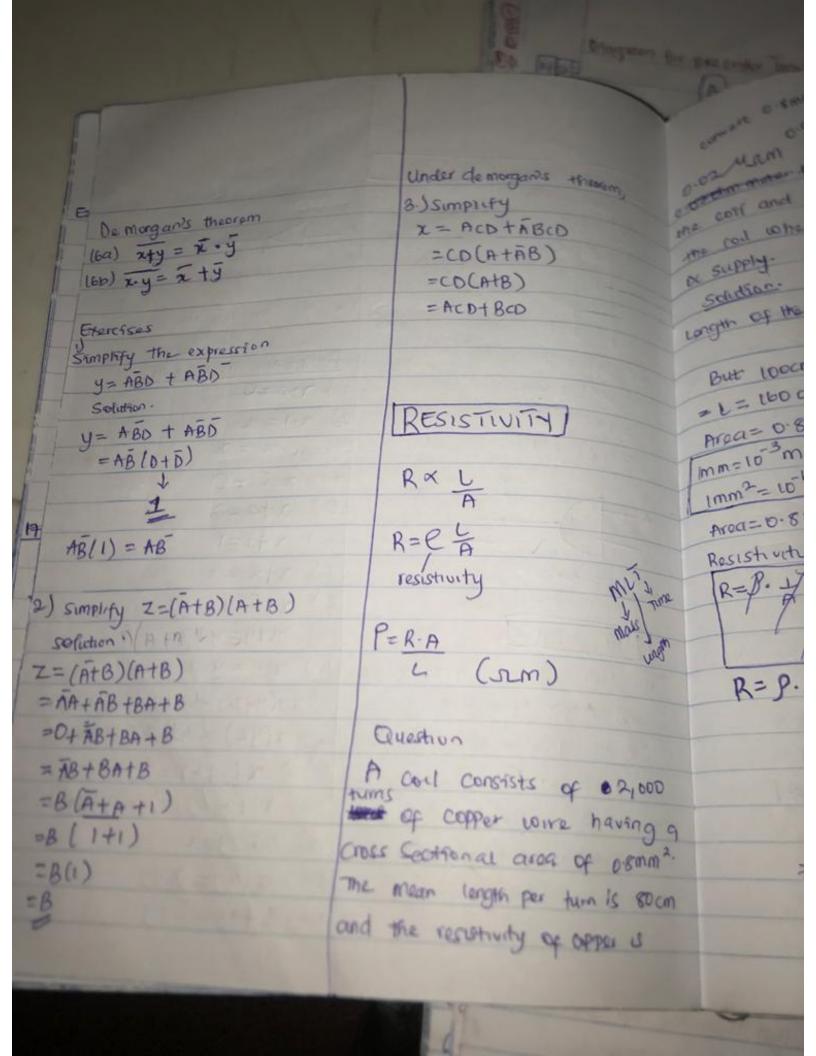
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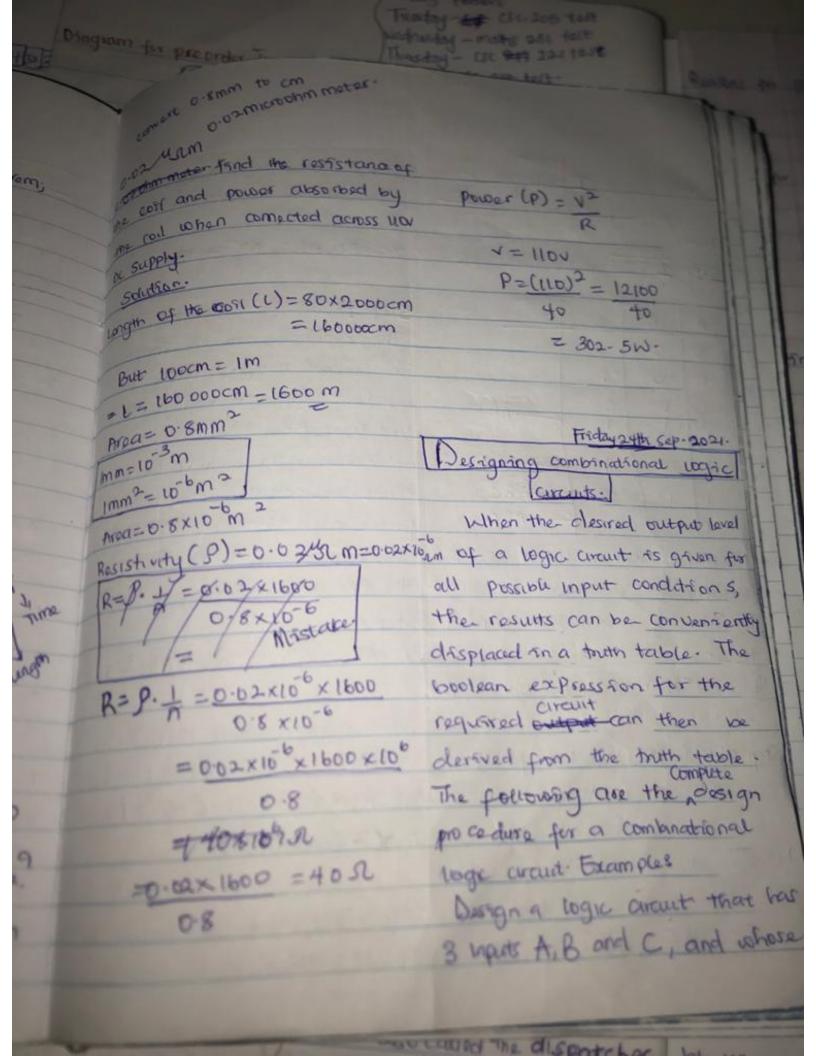




20X1 = 110

The Mi OR and ct can k input vai variable NOT OF





HIGH output will be I high only when the majority of the inputs will high sofution STEP 1 : Set up the truth table

-TBC

NB: outputs will be HIGH when the 1.e where I is more than 01.e 4

0

0 0

times. MB: The (-) Bar shows the Walue is O

Step 2: write the AND term for each case where the output is

NAB: There are 4 Such cases and they are shown in the truth tables te ABC, ABC, ABC and ABC.

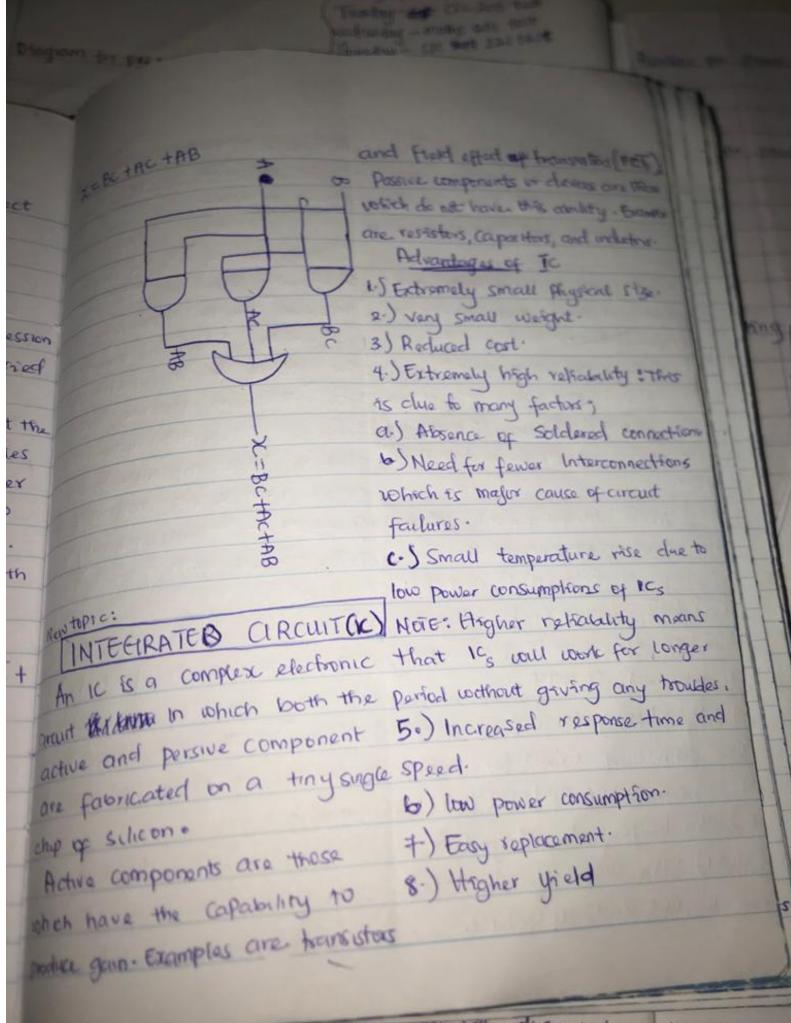
Stop 3: With the Sum of Product expression for the computer. X-ABC, ABC, ABC+ ABC

Step 4: Simplify the cutput expression The expression can be simplified in Several ways. Perhaps, the quickost way is to realise that the last term ABC has two variables in common with each of the other terms We can use ABC term to factor each of the other terms. The expression is rewritten with majority of the INPUTS are high. the ABC term occurring 3 times! Step 4:

X= ABC + ABC + ABC + ABC +

Solve using Boolean theorem. = BC(A+A) + AC(B+B) + AB(T+C) But, AtA, BTB, and C+C = 1 : X= BC +AC+AB

Step 5 i Implement the Circuit for the final expression



as a called the dispatcher, but

blocks or

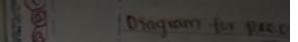
Onebooks (Decade antique) of I/4 6) Euge Scale britagent confession of Constant Property of C Orasbacks Dienchanny of falmentat number of circuit per pretage is A Lines (2) Is functions at fairly low orthoger mallion or more atter by 1/2) They handle only Howled amount of of both Classefucken of Ico by sharing contract of Shudwally sporting. I've can be 4-) They are quite delicate and Tel feet classified into the following, Teamed withstand rough handly or 1.) Monoletrice Integrated auxilia. In executive heat. clasise this type of Is all circuit companie Scale of Integrative @ Line 1. J SSI : Small scaler Integration both active and passive are 30 Dea fabrated inseparably within a sime The number of arcuits obtained in one ic package to loss than piece of subscon crystalline material Lanca canad WATER OR SUBTRATE. AN 10referred 2.) MSJ: Medium Scale Integration Components are automatically part their The number of circuits per IC of the same thip. take Package is between 13 and 99. values 3.] LSI: Large scale integration 2) thick and thin film Ics: Thick gen The no of circusts per I a package than I's are Constructed by mp Es 100 and 9,999. depositing films of conducting Ids (4-) V LSI (very large scale Integration) Materials Through a mast on Their number of circuit per package the Subtrate made of glass Es between 19000 and 99,999. Caramics. 5.) Ultra large Scale integration Thick film Ids: This type of Ids 00 00 ULSI) . The arcuit density is betwo Silk screen printing technique on 100,000 and 999,999. 347 are used to greate desired pattern

Daubocks (Disarbanteges) of Iq 6) Auga Scale integration (45) or 1.) asis or includes cannot be falmental number of circuit per particle at such too rottinger mallion or more MA 12) Its functions at fairly tow vottages million or more 13) They hardle only 15 mited amount of Classification of Ics by structure CHECK Structurally speaking . It's can be 4) they are quite delicate and TO 4 classified into the following canno withstand rough handly or 1.) Monoletric Integrated curit : In excessive heat. class this type of Ic all aren't comprised Scale of Integration @ 15 1.] SSI : Small scaler integration both active and Passive 30 D The number of arcuits obtained fabrated inseparably within a san in one ic package to loss than piece of subscon crystalline material Lan caused WAFER OR SUBTRATE. ALL refer 2.) Ms I: Medium Scale Integration Components are automatically part the The number of circuits per IC of the same ship. +00 Pactage is between 13 and 019. val 3.) LSI: Large Scale integration 2) thick and thin film Ics: Thick The no of arousts per Lapactage than I's are constructed by Es 100 and 9,999. depositing films of conducting To (4-) V LSI (very large scale Integration) Materials Through a mast on Their number of circuit per package the Subtrate made of glass Es between 19000 and 99,999. Cramses. 5.) Ultra large Scale integration Thick film Ids: This type of Ids ULSI): The arcuit density is betwo Silk screen printing technique in 100,000 and 999,999. are used to greate desired pattern

Tracting the City Line tall with makes - mother than the term Charleson for 586 cthe Suppose of the Ich. (11) Street Sugar completions 3) Hybrid Joss. Those are formed by purcer amplifiers by Interconnecting a number 11) RF and If amprificing) : The influented drips or by 9 amb. 1) microcaus comprégient L une extrant of film and monethelies (11) Muttepliers VII) Vottage Comparators To techniques. ture_ VIII) Voltage regulators. , pe classification of Tes by function Digital Integrated arcuits i These O Linear Ids : 10 are mostly used by the computer Digital Jes openent Industry . They lend themselves Linear Integrated arousts: Also easily to monorithic integration referred to as analogue Ic's because because a computer uses a large Single ral their inputs and outputs can · A11 take on a continuous range of Digital I's contains circuits walves and this butputs are whose input and output voltages art generally proportional to the are lamited to two possible values input as combined to degetal Low or high. This is because thick degretal Segments are usually bings. Digital 185 include circuits 6.) They possess higher retability such as ? a) Linear (1) Logic gote because so many external Connections are elemented - They (11.) Hip floops in transmitty used in; (14) Clock-chips e) operational amplifiers

Soms andructure v) calculator chips VU Memory chips VII) Microprocessor. Internitie UY Pure semiconductions mpure sen Constructors 15/00/2021 Frictory Sami conductors. A semi conductor Material is one whose electrical properties lies botw Intrincia us pure semiconduction those of insulations and conductors org An Internessa semiconductor si one Stilscon and gemantum in terms of 10 hach is made up of a Semi energy bands, somi conductors can conductor material in its extremely be defined as Those materials which pure form. Atternatively an inmohave almost an empty conduction SEC Semi conductors may be define band and almost filled valence band with a very namew energy as one in which the no of condugap sopprating the two. Semi ction electron is equal to the no Conductor current &s the sum of of holes. Examples of Such Som electron and hole currents flowing conductors are pure gamanium in opposite directions. and solicon which have ferbidden types of Semin conductors. energy gaps of 0.72 eV and Somi conductors can be classified I lev respectively. as shown helow-The energy gap & so. Small that even at ordinary room temperature, there are many electrons which pluses process sufficient energy

Howard, it is worth noting that for each elation liberated in the control of the 2) Extransfe Somsconductors Those intrinsic some conductors of to which some impurities or supply depend agent or depart has been added an extremely grall amounts are called extrensic or inpure sum conductors The usual doping agents are; a) pentavelent atoms having 5 valence electrons (Arrenic, Antimony phosphosous) or b) invalent alons having 3 valence electrons (galtour, aluminjum, boron Depending unthe type of doping material used, extrinsic sem conductors can be subdivided into (2) electes; 1 H type Somi conductors D p type semi conductor (1) N Mpe This type of Semi conductive is obtained when a pentavaried noterial like anthimony is added to pure genanium crystal. in N type Semi conductors, electrons are the majority carriers while holes Constitute the minority carries. Hence, N type semi anductors concluck Principally by electrons in the nearty electron band and the Process is called excess conduction. the short om scheduling & only. called conserver an event occurs that



This type of Semi conductor is obtained when traces of trivalent material are added to a pure crystal. In this case, the three valence electron of boron atom form covalent bond with four surpunding atoms and one bond is left incomplete and gives rise to a whole holes form negative carriers, constructure postave carriers, constructure postave